PATENT COOPERATION TREATY

PCT

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

REC'D 1 3 JUN 2006

(Chapter II of the Patent Cooperation Treaty)

WIPO PCT

(PCT Artcle 36 and Rule 70)

Applicant's or agent's file reference						
SS-21261-PCT	FOR FURTHER A	CTION	See Form PCT/IPEA/416			
International application No. PCT/KR2005/000357	International filing date 05 FEBRUARY 2	2005 (05.02.2005)	Priority date (day/month/year) 17 FEBRUARY 2004 (17.02.2004)			
International Patent Classification (IPC) or national classification	n and IPC				
H01L 29/78(2006.01)i, H01L	21/335(2006.01)i, H0	01L 21/336(2006.01))i			
Applicant						
SAMSUNG ELECTRONICS	CO., LTD. et al		•			
 This report is the international pr Authority under Article 35 and tr 	eliminary examination rep	port, established by this I	international Preliminary Examining			
2. This REPORT consists of a total	of4 sheets	s. including this cover sh	eet			
 This report is also accompanied ! 	by ANNEXES, comprising	σ· .	, ,			
a. (sent to the applicant and	d to the International Bure	au) a total of	sheets, as follows:			
sheets of the descand/or sheets con Administrative In	aming recuireding and	wings which have harm	amended and are the basis for this repor (see Rule 70.16 and Section 607 of the			
sheets which supe	ersede earlier sheets, but w	which this Authority con-	siders contain an amendment that goes			
beyond the disclo Supplemental Box	ouro mi uno miternamentali al	pplication as filed, as inc	licated in item 4 of Box No. I and the			
b. (sent to the International	l Bureau only) a total of G	ndicate time and				
ontaining a sequence his	sting and/or tables related a Listing (see Section 802	thereto in electronia for				
0 11	——————————————————————————————————————	of the Administrative in	structions).			
This report contains indications re	lating to the following iter	ms:				
	sis of the report					
	Priority					
Box`No. III Non-establis	of opinion with regard to noverty, inventive step and industrial applicability					
Box No. IV Lack of unit	. IV Lack of unity of invention					
Box No. V Reasoned st citations and	atement under Article 35(explanations supporting s	2) with regard to novelty	, inventive step or industrial applicabilit			
Box No. VI Certain docu	soned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; ions and explanations supporting such statement tain documents cited					
Box No. VII Certain defec	ects in the international application					
	servations on the international application					
e of submission of the demamd		Date of completion of the	nis report			
15 SEPTEMBER 2005	(15.09.2005)	25 MAY 2006	(25.05.2006)			
me and mailing address of the IPEA/KR		Authorized officer				
Korean Intellectual Property Office 920 Dunsan-dong, Seo-gu, Daejeon 302-701, Republic of Korea		KIM, Keun Mo	AR			
simile No. 82-42-472-7140		Telephone No. 82-42-4	81-5985			

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

PCT/KR2005/000357

ox No. I	Basis of the report	
others	egard to the language, this report is based on the international application in the langua ise indicated under this item. This report is based on translations from the original language into the following langua	
Ш,	which is the language of a translation furnished for the purposes of:	
	international search (under Rules 12.3 and 23.1(b))	
	publication of the international application (under Rule 12.4)	
	international preliminary examination (under Rules 55.2 and/or 55.3)	
to the	egard to the elements of the international application, this report is based on <i>(replacemoreceiving Office in response to an invitation under Article 14 are referred to in this reored to this report): the international application as originally filed/furnished</i>	ent sheets which hàve been furnished rt as` "originally filed" and are not
	the description:	as originally filed/furnished
	pages received by this Authority on	
	pages* received by this Authority on pages*	
	Puber	
	the claims:	as originally filed/furnished
	pages as amended (together v	with any statment) under Article 19
	pages* received by this Authority on	
	pages* received by this Authority on	
		`
	the drawings: pages	as originally filed/furnished
	pages received by this Authority on	
	pages*	
i	The amendments have resulted in the cancellation of: the description, pages the claims, Nos. the drawings, sheets the sequence listing (specify): any table(s) related to sequence listing (specify):	
l. 🔲	This report has been established as if (some of) the amendments annexed to this report made, since they have been considered to go beyond the disclosure as filed, as indicate (Rule 70.2(c)). the description, pages	ea in the Supplemental Box
* If ite	m 4 applies, some or all of those sheets may be marked "superseded."	

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

YES

NO

PCT/KR2005/000357

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1. Statement

Novelty (N)

Claims 1-37

Claims NONE

ONE

Inventive step (IS)

Claims 1-37

NONE YES NO

Industrial applicability (IA)

Claims $\frac{1}{N}$

Claims

1-37 YES NONE NO

2. Citations and explanations (Rule 70.7)

1) Reference is made to the following documents:

D5 : KR 2004-75566 A

2) Novelty and Inventive Step

The present application is related to a semiconductor device comprising: a first active region comprising a plurality of slabs formed on a substrate, each slab having a first surface, a second surface facing a direction opposite to the first surface, and a top surface: a second active region contacting at least one end of the slabs on the substrate to connect one another; a gate line on the first surface, the second surface and the top surface of each of the slabs; and a gate dielectric layer interposed between the slabs and the gate line (claims 1-18) and a manufacturing method thereof (claims 19-37).

Each of documents mentioned in 1) discloses semiconductor devices having multi gates. But, none of the documents D1 to D5 discloses a semiconductor device in which a second active region(140a) contacting at least one end of the slabs on the substrate to connect one another is formed.

By dividing the active region into a first and a second active regions in which the second active region is formed to connect each other of the slabs, a rounding phenomenon or a 'not open' phenomenon can be avoided in this invention.

As mentioned above, it is considered that D1-D5 are to be little relevant to the semiconductor device (claims 1-18) and the manufacturing method the same (claims 19-37).

- continued -

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

PCT/KR2005/000357

	Sup	plem	ental	Box
--	-----	------	-------	-----

In case the space in any of the preceding boxes is not sufficient. Continuation of:

BOX V

Compared with the prior art as cited in the International Search Report, the present invention(claims 1-37) is believed to be novel and to involve an inventive step under PCT Article 33(2) and 33(3).

3) Industrial Applicability
And the present invention has industrial applicability under PCT Article 33(4).